## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application		)	PATENT APPLICATION
Inventors:	Mokhlesi, et al.	)	Art Unit: 2827
Application No.:	10/762,181	)	Examiner: Hoang, Huan
Filed Date:	January 21, 2004	)	
Title: NON-VOL	ATILE MEMORY CE	LL)	Customer No.: 28554
USING HIG	GH-K MATERIAL AN	ND)	
INTER-GA	TE PROGRAMMING	i )	
		)	

## STATEMENT OF THE SUBSATNCE OF INTERVIEW

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

This Statement of the Substance of Interview is being filed in reply to the Interview Summary mailed on September 19, 2006.

On August 24, 2006 and August 31, 2006, Applicant's undersigned attorney participated in telephone conferences with Huan Hoang, at which time three prior art references were discussed with respect to all of the claims:

- (1) U.S. Patent 6,784,484 ("the '484 Patent");
- (2) U.S. Patent 6,790,782 ("the '782 Patent:); and
- (3) "An Empirical Model for Charge Leakage Through Oxide-Nitride-Oxide Interpoly Dielectric In Stacked Gate Flash Memory Devices," Jang Han Kim, Jung Bum Choi, Bong Jo Shin and Keun Hyung Park, Semiconductor Science and Technology 18 (2003) pp. 158-162 ("the Jang Han Kim Article").

The '782 Patent was previously disclosed to the Examiner by the Applicant in an IDS. The '484 Patent and the Jang Han Kim Article were identified by the Examiner during the

telephone call on August 24, 2006.

During that telephone conference, Applicant agreed to the amendments depicted in the Examiner's Amendment that accompanied the Interview Summary mailed on September 19,

2006. The Examiner and the Applicant agreed that the claims, as amended in the Examiner's

Amendment, are allowable over the prior art.

The Examiner told Applicant's undersigned Attorney that the Examiner would be

sending out a Supplemental Notice of Allowability and a Notice of References Cited. Applicant notes that the Examiner has not yet sent out the Notice of References Cited. Therefore,

Applicant respectfully requests that the Examiner send out a Notice of References Cited for U.S.

Patent 6,784,484 and the Jang Han Kim Article.

Applicant believes that no fee is due with this paper. However, the Commissioner is

authorized to charge any underpayment or credit any overpayment to Deposit Account No.

501826 for any matter in connection with this document, including any fee for extension of time,

which may be requested.

Respectfully submitted,

Date:	October 9, 2006	By:	/Burt Magen/
			Burt Magen
			Reg. No. 37,175

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